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### FJNS3202R

### Switching Application (Bias Resistor Built In)

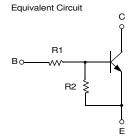
- Switching circuit, Inverter, Interface circuit, Driver Circuit
- Built in bias Resistor ( $R_1=10K\Omega$ ,  $R_2=10K\Omega$ )
- Complement to FJNS4202R



## **NPN Epitaxial Silicon Transistor**

### **Absolute Maximum Ratings** $T_a$ =25°C unless otherwise noted

| Symbol           | Parameter                   | Value     | Units |
|------------------|-----------------------------|-----------|-------|
| V <sub>CBO</sub> | Collector-Base Voltage      | 50        | V     |
| V <sub>CEO</sub> | Collector-Emitter Voltage   | 50        | V     |
| V <sub>EBO</sub> | Emitter-Base Voltage        | 10        | V     |
| I <sub>C</sub>   | Collector Current           | 100       | mA    |
| P <sub>C</sub>   | Collector Power Dissipation | 300       | mW    |
| T <sub>J</sub>   | Junction Temperature        | 150       | °C    |
| T <sub>STG</sub> | Storage Temperature         | -55 ~ 150 | °C    |



## **Electrical Characteristics** $T_a$ =25°C unless otherwise noted

| Symbol                         | Parameter                            | Test Condition                                      | Min. | Тур. | Max. | Units |
|--------------------------------|--------------------------------------|---|------|------|------|-------|
| BV <sub>CBO</sub>              | Collector-Base Breakdown Voltage     | $I_{C}=10\mu A, I_{E}=0$                            | 50   |      |      | V     |
| BV <sub>CEO</sub>              | Collector-Emitter Breakdown Voltage  | $I_{C}=100\mu A, I_{B}=0$                           | 50   |      |      | V     |
| I <sub>CBO</sub>               | Collector Cut-off Current            | $V_{CB}=40V$ , $I_{E}=0$                            |      |      | 0.1  | μΑ    |
| h <sub>FE</sub>                | DC Current Gain                      | V <sub>CE</sub> =5V, I <sub>C</sub> =5mA            | 30   |      |      |       |
| V <sub>CE</sub> (sat)          | Collector-Emitter Saturation Voltage | I <sub>C</sub> =10mA, I <sub>B</sub> =0.5mA         |      |      | 0.3  | V     |
| f <sub>T</sub>                 | Current Gain Bandwidth Product       | V <sub>CE</sub> =10V, I <sub>C</sub> =5mA           |      | 250  |      | MHz   |
| C <sub>ob</sub>                | Output Capacitance                   | V <sub>CB</sub> =10V, I <sub>E</sub> =0<br>f=1.0MHz |      | 3.7  |      | pF    |
| V <sub>I</sub> (off)           | Input Off Voltage                    | $V_{CE}=5V, I_{C}=100\mu A$                         | 0.5  |      |      | V     |
| V <sub>I</sub> (on)            | Input On Voltage                     | $V_{CE}$ =0.3V, $I_{C}$ =10mA                       |      |      | 3    | V     |
| R <sub>1</sub>                 | Input Resistor                       |   | 7    | 10   | 13   | ΚΩ    |
| R <sub>1</sub> /R <sub>2</sub> | Resistor Ratio                       |   | 0.9  | 1    | 1.1  |       |

# **Typical Characteristics**

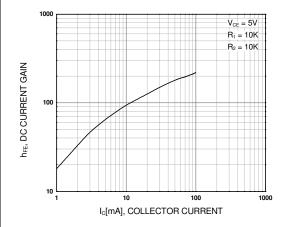


Figure 1. DC current Gain

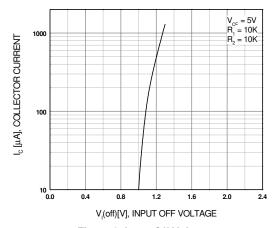


Figure 3. Input Off Voltage

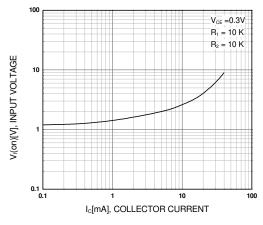


Figure 2. Input On Voltage

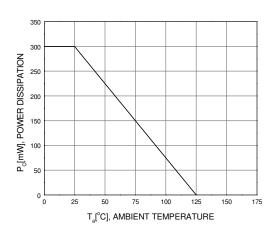
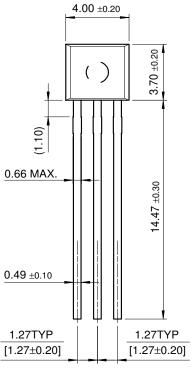
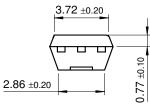


Figure 4. Power Derating

**TO-92S** 







Dimensions in Millimeters

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| EnSigna™             | LittleFET™          | QS™                      | TinyLogic™            |            |
| FACT™                | MicroFET™           | QT Optoelectronics™      | TruTranslation™       |            |
| FACT Quiet series™   | MicroPak™           | Quiet Series™            | UHC™                  |            |
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